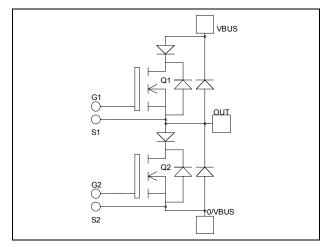
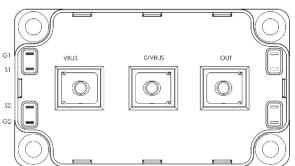


Phase leg Series & parallel diodes MOSFET Power Module

$$\begin{split} V_{DSS} &= 1000 V \\ R_{DSon} &= 130 m \Omega \text{ typ @ Tj} = 25^{\circ} C \\ I_D &= 65 A \text{ @ Tc} = 25^{\circ} C \end{split}$$





Application

- Motor control
- Switched Mode Power Supplies
- Uninterruptible Power Supplies

Features

- Power MOS 7[®] MOSFETs
 - Low R_{DSon}
 - Low input and Miller capacitance
 - Low gate charge
 - Fast intrinsic reverse diode
 - Avalanche energy rated
 - Very rugged
- Kelvin source for easy drive
- Very low stray inductance
 - Symmetrical design
 - M5 power connectors
- High level of integration

Benefits

- Outstanding performance at high frequency operation
- Direct mounting to heatsink (isolated package)
- Low junction to case thermal resistance
- Low profile
- RoHS Compliant

All ratings @ $T_i = 25^{\circ}C$ unless otherwise specified

Absolute maximum ratings

| Symbol | Parameter | | Max ratings | Unit |
|-------------------|---|---------------------|-------------|------|
| $V_{ m DSS}$ | Drain - Source Breakdown Voltage | | 1000 | V |
| т | Continue David Comment | $T_c = 25^{\circ}C$ | 65 | |
| I_D | Continuous Drain Current | $T_c = 80$ °C | 49 | A |
| I_{DM} | Pulsed Drain current | ě | | |
| V_{GS} | Gate - Source Voltage | | ±30 | V |
| R _{DSon} | Drain - Source ON Resistance | | 156 | mΩ |
| P_{D} | Maximum Power Dissipation | $T_c = 25^{\circ}C$ | 1250 | W |
| I_{AR} | Avalanche current (repetitive and non repetitive) | | 24 | A |
| E_{AR} | Repetitive Avalanche Energy | | 30 | mJ |
| E_{AS} | Single Pulse Avalanche Energy | | 1300 | 1113 |

These Devices are sensitive to Electrostatic Discharge. Proper Handling Procedures Should Be Followed. See application note APT0502 on www.microsemi.com



Electrical Characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|---------------------|---------------------------------|---|---------------------------------------|-----|-----|------|------|
| I_{DSS} | Zero Gate Voltage Drain Current | $V_{GS} = 0V, V_{DS} = 1000V$ T | $\Gamma_{\rm j} = 25^{\circ}{\rm C}$ | | | 600 | μΑ |
| | | $V_{GS} = 0V, V_{DS} = 800V$ T | $\Gamma_{\rm j} = 125^{\circ}{\rm C}$ | | | 2 | mA |
| R _{DS(on)} | Drain – Source on Resistance | $V_{GS} = 10V, I_D = 32.5A$ | | | 130 | 156 | mΩ |
| $V_{GS(th)}$ | Gate Threshold Voltage | $V_{GS} = V_{DS}$, $I_D = 6mA$ | | 3 | | 5 | V |
| I_{GSS} | Gate – Source Leakage Current | $V_{GS} = \pm 30 \text{ V}, V_{DS} = 0 \text{ V}$ | | · | | ±450 | nA |

Dynamic Characteristics

| Symbol | Characteristic | Test Conditions | Min | Тур | Max | Unit |
|------------------|-------------------------------------|--|-----|------|-----|------|
| C_{iss} | Input Capacitance | $V_{GS} = 0V$ | | 15.2 | | |
| C_{oss} | Output Capacitance | $V_{\rm DS} = 25 V$ | | 2.6 | | nF |
| C_{rss} | Reverse Transfer Capacitance | f = 1MHz | | 0.42 | | |
| $Q_{\rm g}$ | Total gate Charge | $V_{GS} = 10V$ | | 562 | | |
| $Q_{\rm gs}$ | Gate – Source Charge | $V_{\text{Bus}} = 500V$ | | 75 | | nC |
| Q_{gd} | Gate – Drain Charge | $I_D = 65A$ | | 363 | | |
| $T_{d(on)}$ | Turn-on Delay Time | Inductive switching @ 125°C | | 9 | | |
| $T_{\rm r}$ | Rise Time | $V_{GS} = 15V$ | | 9 | | |
| $T_{d(off)}$ | Turn-off Delay Time | $V_{\text{Bus}} = 667V$ $I_{\text{D}} = 65A$ | | 50 | | ns |
| T_{f} | Fall Time | $R_G = 0.5\Omega$ | | 24 | | |
| Eon | Turn-on Switching Energy | Inductive switching @ 25°C | | 2.13 | | |
| E_{off} | Turn-off Switching Energy | $V_{GS} = 15V, V_{Bus} = 667V$ $I_D = 65A, R_G = 0.5\Omega$ | | 0.46 | | mJ |
| Eon | Turn-on Switching Energy | Inductive switching @ 125°C | | 4.4 | | T |
| E_{off} | Turn-off Switching Energy | $V_{GS} = 15V, V_{Bus} = 667V$ $I_D = 65A, R_G = 0.5\Omega$ | | 0.57 | | mJ |
| R_{thJC} | Junction to Case Thermal Resistance | | | | 0.1 | °C/W |

Series diode ratings and characteristics

| Symbol | Characteristic | aracteristic Test Conditions | | Min | Тур | Max | Unit |
|-----------------|---|--------------------------------------|------------------------|------|------|------|------|
| V_{RRM} | Maximum Repetitive Reverse Voltage | e | | 1000 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 1000V$ | | | | 350 | μA |
| I_F | DC Forward Current | | $T_{c} = 100^{\circ}C$ | | 120 | | A |
| | | $I_F = 120A$ | | | 1.9 | 2.5 | |
| $V_{\rm F}$ | Diode Forward Voltage | $I_F = 240A$ | | | 2.2 | | V |
| | | $I_F = 120A$ | $T_j = 125$ °C | | 1.7 | | |
| + | t_{rr} Reverse Recovery Time $I_F = 120A$ | $T_j = 25$ °C | | 280 | | ns | |
| ι _{rr} | | $I_F = 120A$ $V_R = 667V$ $T_j =$ | $T_j = 125$ °C | | 350 | | 115 |
| Q _{rr} | Reverse Recovery Charge | $di/dt = 400A/\mu s$ | $T_j = 25$ °C | | 1520 | | пC |
| | | | $T_j = 125^{\circ}C$ | | 7200 | | пс |
| R_{thJC} | Junction to Case Thermal Resistance | | | | | 0.46 | °C/W |



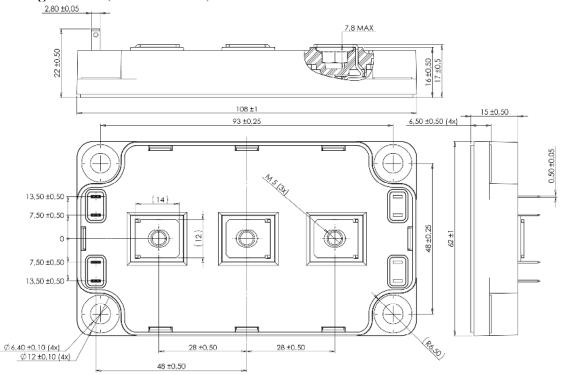
Parallel diode ratings and characteristics

| Symbol | Characteristic | Test Conditions | | Min | Typ | Max | Unit |
|------------------|-------------------------------------|-----------------------------------|------------------------|------|------|------|------|
| V_{RRM} | Maximum Repetitive Reverse Voltage | aximum Repetitive Reverse Voltage | | 1000 | | | V |
| I_{RM} | Maximum Reverse Leakage Current | $V_R = 1000V$ | | | | 350 | μA |
| I_{F} | DC Forward Current | | $T_c = 100$ °C | | 120 | | A |
| | | $I_{\rm F} = 120A$ | | | 1.9 | 2.5 | |
| V_{F} | Diode Forward Voltage | $I_F = 240A$ | | | 2.2 | | V |
| | | $I_F = 120A$ | $T_j = 125$ °C | | 1.7 | | |
| 4 | Reverse Recovery Time | | $T_j = 25$ °C | | 280 | | |
| t_{rr} | | $I_F = 120A$ $V_R = 667V$ | $T_{j} = 125^{\circ}C$ | | 350 | | ns |
| 0 | | $di/dt = 400A/\mu s$ | $T_j = 25$ °C | | 1520 | | пC |
| Qrr | | • | $T_{j} = 125^{\circ}C$ | | 7200 | | IIC |
| R_{thJC} | Junction to Case Thermal Resistance | | _ | | | 0.46 | °C/W |

Thermal and package characteristics

| Symbol | Characteristic | | | Min | Typ | Max | Unit |
|------------|---|------------------|----|-----|-----|-----|--------|
| V_{ISOL} | RMS Isolation Voltage, any terminal to case t =1 min, 50/60Hz | | | | | | V |
| T_{J} | Operating junction temperature range | | | -40 | | 150 | |
| T_{STG} | Storage Temperature Range | | | | | 125 | °C |
| T_{C} | Operating Case Temperature | Case Temperature | | | | | |
| Torque | Mounting torque | To heatsink | M6 | 3 | | 5 | N.m |
| Torque | Mounting torque For terminals M | | M5 | 2 | | 3.5 | 18.111 |
| Wt | Package Weight | | | | | 300 | g |

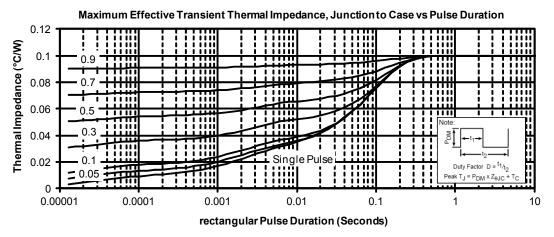
SP6 Package outline (dimensions in mm)

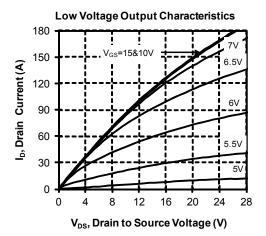


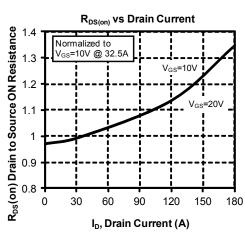
See application note APT0601 - Mounting Instructions for SP6 Power Modules on www.microsemi.com

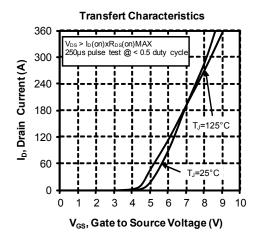


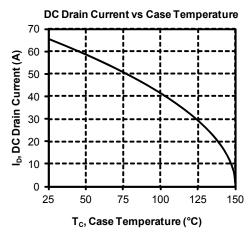
Typical Performance Curve



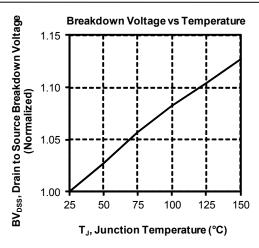


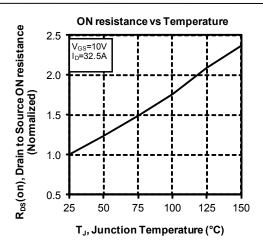


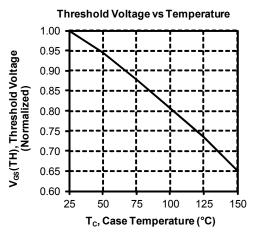


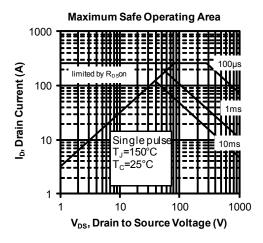


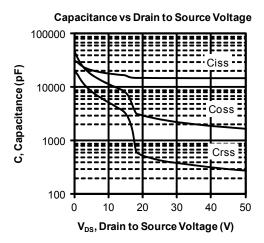


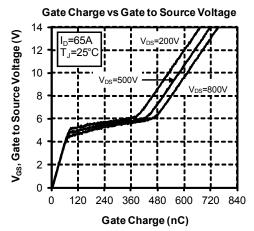




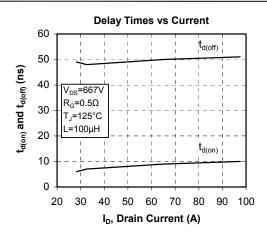


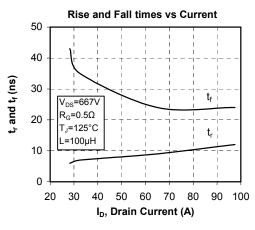


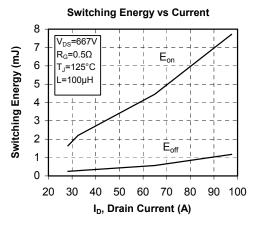


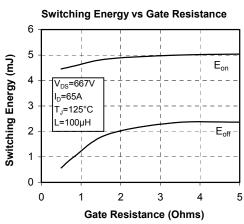


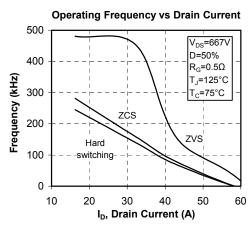


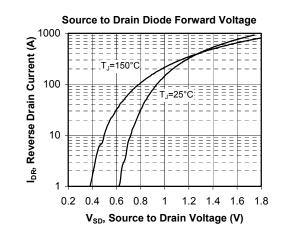














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